GREEN (5-2008)**



Vishay Semiconductors

Silicon NPN Phototransistor



DESCRIPTION

TEKT5400S is a silicon NPN phototransistor with high radiant sensitivity, molded in a plastic package with side view lens and daylight blocking filter. Filter bandwidth is matched with 950 nm IR emitters.

FEATURES

- Package type: leaded
- Package form: side view lens
- Dimensions (L x W x H in mm): 5 x 2.65 x 5
- High radiant sensitivity
- Daylight blocking filter matched with 940 nm emitters
- Fast response times
- Angle of half sensitivity: φ = ± 37°
- Package matched with IR emitter series TSKS5400S
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC



** Please see document "Vishay Material Category Policy": www.vishay.com/doc?99902

APPLICATIONS

· Detector in electronic control and drive circuits

| PRODUCT SUMMARY | | | |
|-----------------|----------------------|---------|-----------------------|
| COMPONENT | I _{ca} (mA) | φ (deg) | λ _{0.5} (nm) |
| TEKT5400S | 4 | ± 37 | 850 to 980 |

Note

· Test condition see table "Basic Characteristics"

| ORDERING INFORMATION | | | | |
|----------------------|-----------|------------------------------|----------------|--|
| ORDERING CODE | PACKAGING | REMARKS | PACKAGE FORM | |
| TEKT5400S | Bulk | MOQ: 2000 pcs, 2000 pcs/bulk | Side view lens | |

Note

• MOQ: minimum order quantity

| ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified) | | | | | |
|--|--|-------------------|---------------|------|--|
| PARAMETER | TEST CONDITION | SYMBOL | VALUE | UNIT | |
| Collector emitter voltage | | V _{CEO} | 70 | V | |
| Emitter collector voltage | | V _{ECO} | 7 | V | |
| Collector current | | I _C | 100 | mA | |
| Collector peak current | $t_p/T \le 0.5, t_p \le 10 \text{ ms}$ | I _{CM} | 200 | mA | |
| Power dissipation | T _{amb} ≤ 40 °C | P _V | 150 | mW | |
| Junction temperature | | Tj | 100 | °C | |
| Operating temperature range | | T _{amb} | - 40 to + 85 | °C | |
| Storage temperature range | | T _{stg} | - 40 to + 100 | °C | |
| Soldering temperature | t ≤ 5 s | T _{sd} | 260 | °C | |
| Thermal resistance junction/ambient | J-STD-051, soldered on PCB | R _{thJA} | 270 | K/W | |



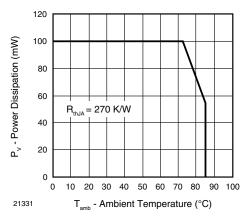


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

| BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified) | | | | | | |
|---|---|--------------------|------|------------|------|------|
| PARAMETER | TEST CONDITION | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| Collector emitter voltage | $I_C = 1 \text{ mA}$ | V_{CEO} | 70 | | | V |
| Emitter collector voltage | I _E = 100 μA | V _{ECO} | 7 | | | V |
| Collector dark current | $V_{CE} = 20 \text{ V}, E = 0$ | I _{CEO} | | 1 | 100 | nA |
| Collector emitter capacitance | $V_{CE} = 5 \text{ V, } f = 1 \text{ MHz, } E = 0$ | C _{CEO} | | 6 | | рF |
| Collector ligth current | E_e = 1 mW/cm ² , λ = 950 nm, V_{CE} = 5 V | I _{ca} | 2 | 4 | | mA |
| Angle of half sensitivity | | φ | | ± 37 | | deg |
| Wavelength of peak sensitivity | | λ _p | | 920 | | nm |
| Range of spectral bandwidth | | λ _{0.5} | | 850 to 980 | | nm |
| Collector emitter saturation voltage | $E_e = 1 \text{ mW/cm}^2$, $\lambda = 950 \text{ nm,I}_C = 0.1 \text{ mA}$ | V _{CEsat} | | | 0.3 | V |
| Turn-on time | $V_{S} = 5 \text{ V}, I_{C} = 5 \text{ mA}, R_{L} = 100 \Omega$ | t _{on} | | 6 | | μs |
| Turn-off time | $V_S = 5 \text{ V}, I_C = 5 \text{ mA}, R_L = 100 \Omega$ | t _{off} | | 5 | | μs |
| Cut-off frequency | $V_S = 5 \text{ V}, I_C = 5 \text{ mA}, R_L = 100 \Omega$ | f _c | | 110 | | kHz |

BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

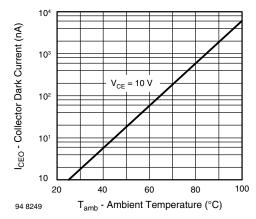


Fig. 1 - Collector Dark Current vs. Ambient Temperature

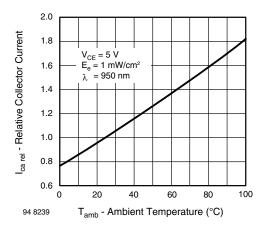


Fig. 2 - Relative Collector Current vs. Ambient Temperature



Vishay Semiconductors

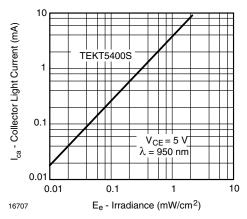


Fig. 3 - Collector Light Current vs. Irradiance

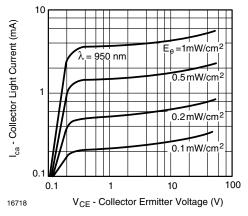


Fig. 4 - Collector Light Current vs. Collector Emitter Voltage

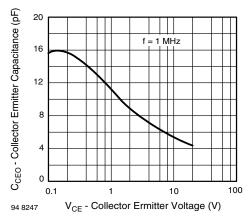


Fig. 5 - Collector Emitter Capacitance vs. Collector Emitter Voltage

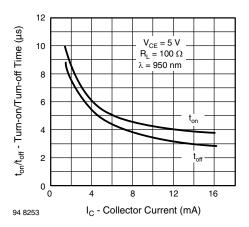


Fig. 6 - Turn-on/Turn-off Time vs. Collector Current

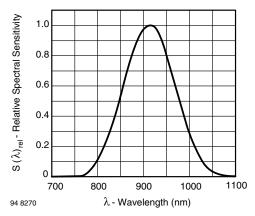


Fig. 7 - Relative Spectral Sensitivity vs. Wavelength

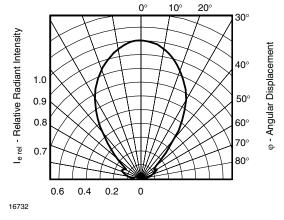
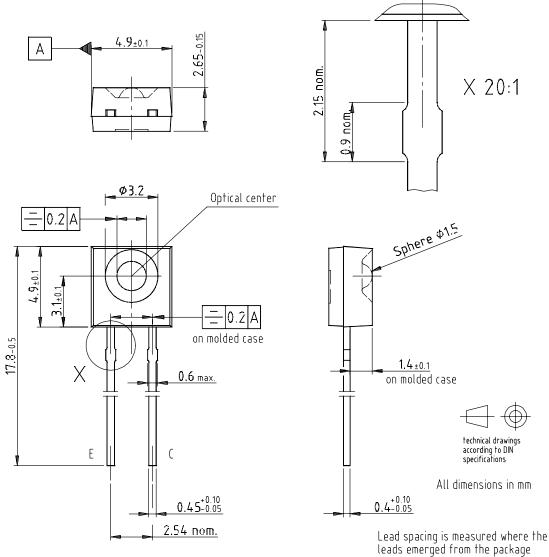


Fig. 8 - Relative Radiant Intensity vs. Angular Displacement



Vishay Semiconductors

PACKAGE DIMENSIONS in millimeters



Drawing-No.: 6.544-5347.01-4

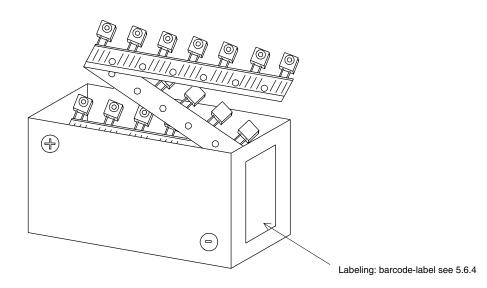
Issue: 2; 09.04.03

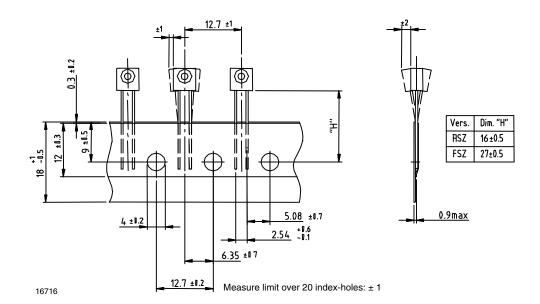
Protruded resin area where the leads emerged from the package 0.8 max.

16706



TAPE AND AMMOPACK STANDARDS Dimensions in millimeters







Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Vishay products are not designed for use in life-saving or life-sustaining applications or any application in which the failure of the Vishay product could result in personal injury or death unless specifically qualified in writing by Vishay. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.